500-6000 MHz 50Ω

The Big Deal

- Wide bandwidth 500 to 6000 MHz
- Very high isolation, 65 dB at 1GHz
- Very fast switching, 35ns



Product Overview

The ZFSWA2-63DR+ / ZFSWA2R-63DR+ is a great general purpose SPDT solid state absorptive RF switch. With its broad frequency range, fast 35 ns switching time and excellent RF performance, the ZFSWA2-63DR+ / ZFSWA2R-63DR+ is an excellent choice for many applications. In addition to it's versatility within system block diagrams, the ZFSWA2-63DR+ / ZFSWA2R-63DR+ is designed for easy integration into your prototype design applications. ZFSWA2-63DR+ is the standard configuration. ZFSWA2R-63DR+ is the mirrored configuration with RF1 and RF2 ports interchanged.

Key Features

Feature	Advantages
Designed for any environment	The ZFSWA2-63DR+ / ZFSWA2R-63DR+ is equipped with MMIC internal device with a wide operating temperature range (-55°C to 100°C). Suitable for many environments and applications the ZFSWA2-63DR+ / ZFSWA2R-63DR+ offers excellent performance and value.
Integrated CMOS Driver	-Operates from 3-5V -Low control current 5 µA allows compatibility with a variety of driver circuits -Internal Decoupling -Fast 35 ns Switching time
Excellent for a Variety of Applications From Bench to Integrated Systems	-High speed testers -Automated switching networks -Wireless Infrastructure -Military
Excellent RF Performance	-Wide bandwidth: 500 to 6000 MHz -Low Insertion Loss: 1.4 dB Typ -High Isolation: 65 dB Typ @ 1 GHz

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SPDT RF Switch

50Ω 500-6000 MHz

Absorptive RF Switch with Internal Driver Single Supply Voltage, +3V to +5V

Product Features

- Wide bandwidth, 500 to 6000 MHz
- High Isolation, 65 dB typ. at 1 GHz
- Low Insertion loss, 1.4 dB typ.
- Internal CMOS driver
- Fast switching, Rise/fall time, 25 ns typ.
- Wide operating temperature, -55°C to 100°C

Typical Applications

- Cellular
- ISM, WCDMA, WIMAX
- PCN
- · Automated switching networks
- Military



CASE STYLE: ZZ1322

 Connectors
 Model

 SMA
 ZFSWA2-63DR+
 (Standard option)

 SMA
 ZFSWA2R-63DR+
 (RF Ports Reversed)

 BRACKET
 (OPTION "B")

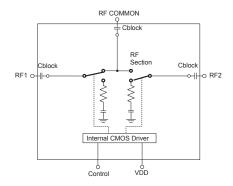
+RoHS Compliant

The +Suffix identifies RoHS Compliance. See our web site for RoHS Compliance methodologies and qualifications

General Description

The ZFSWA2-63DR+ / ZFSWA2R-63DR+ is a 50Ω high isolation, absorptive SPDT RF switch designed for wireless applications, covering a broad frequency range from 500 to 6000 MHz with low insertion loss. The ZFSWA2-63DR+ / ZFSWA2R-63DR+ operates on a single supply voltage in the range of +3V to +5V. This unit includes an internal CMOS driver. The ZFSWA2-63DR+ / ZFSWA2R-63DR+ switch comes with a internal MMIC device for tough environments. ZFSWA2-63DR+ is the standard configuration. ZFSWA2R-63DR+ is the mirrored configuration with RF1 and RF2 ports interchanged.

Schematic and Application Circuit



Notes

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RF Electrical Specifications, 500 - 6000 MHz, T_{AMB} =25°C, V_{DD} = +3V to +5V

Parameter	Condition	Min.	Тур.	Max.	Units
Frequency Range		500		6000	MHz
	500 MHz		1.0	1.3	
	1000 MHz		1.15	1.5	
Insertion Loss	2000 MHz		1.4	1.7	dB
	4000 MHz		1.7	2.1	
	6000 MHz		2.0	2.6	
	500 to 2000 MHz	50	65		I.D.
Isolation between Common port and RF1/RF2 Ports	2000 to 4000 MHz	48 35	57 45		dB
	4000 to 6000 MHz 500 to 2000 MHz	50	60		
Isolation between RF1 and RF2 ports	2000 to 4000 MHz	43	50		dB
isolation between hi i and hF2 ports	4000 to 6000 MHz	35	45		u.b
	500 to 2000 MHz		20		
Return Loss (ON STATE)	2000 to 4000 MHz		17		dB
	4000 to 6000 MHz		15		
	500 to 2000 MHz		17		dB
Return Loss @ RF1/RF2 ports (OFF STATE)	2000 to 4000 MHz		19		
	4000 to 6000 MHz		16		
	V _{DD} =3V, 500 to 2000 MHz		47		dBm
Input IP3	2000 to 6000 MHz		40		
	V _{DD} =5V, 500 to 2000 MHz		49		
	2000 to 6000 MHz V _{DD} =3V, 500 to 2000 MHz		24		
	2000 to 6000 MHz		24		dBm
Input 1dB Compression (1)	V _{DD} =5V, 500 to 2000 MHz		30		
	2000 to 6000 MHz		27		
1	DC Electrical Specification	S			•
VDD, Supply Voltage		3		5	V
Supply Current (2)	V _{DD} =5V		50		μΑ
Control Voltage Low		0		0.5	V
Control Voltage High (3)		2.7 ⁽⁴⁾		V _{DD}	V
Control Current			5		μΑ
	Switching Specifications				
Rise/Fall Time (10 to 90% or 90 to 10% RF)	V _{DD} =5V		25		nSec
Switching Time (50% CTRL to 90/10% RF)	V _{DD} =5V		35		nSec
Video Feed through (Control 0-5V, Frequency 1 MHz)	V _{DD} =5V		30		mV _{P-P}

Absolute Maximum Ratings

Parameter	Ratings	
Operating Temperature	-55°C to 100°C	
Storage Temperature	-55°C to 100°C	
V _{DD} , Supply Voltage	2.7 to 5.5V	
Voltage Control	-0.2V Min. V _{DD} Max.	
RF input power	1Watt	
Dissipated Power at 25°C	370mW	
ESD, HBM	Class 1A (250 to <500V) per JESD22-A114	
ESD, MM	Class A (passes 50V) per JESD22-A115	
ESD, CDM	Class III (500 to <1000V) per JESD22-C101	

^{1.} Note absolute maximum rating for input and dissipated power. At 5V, over 2000-6000 MHz, 0.2 dB compression. 2. Increases with switching repetition rate. See graph.

^{3.} CMOS interface latch-up condition may occur when logic high signal is applied prior to power supply.

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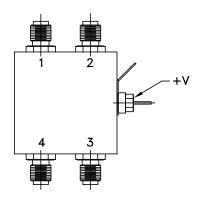
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Truth Table (State of control voltage selects the desired switch state)

State of Control Voltage	Switch State - RF Common to		
State of Control Voltage	RF1	RF2	
Low	ON	OFF	
High	OFF	ON	
ON- low insertion loss state OFF- Isolation State			

Coaxial Configuration

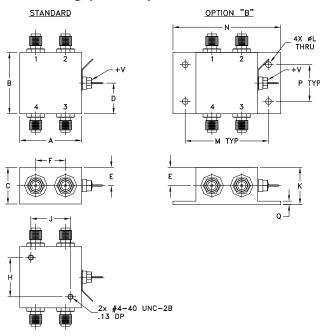


Coaxial Connections

	ZFSWA2R-63DR+	ZFSWA2-63DR+	Description	
Function	Port Number	Port Number		
RF COM	1	1	RF Common/ SUM Port	
RF1	3	4	RF Out #1/In Port #1	
RF2	4	3	RF Out #2/In Port #2	
Control	2	2	CMOS Control IN	
VDD	V+	V+	Supply Voltage	
GND	Case	Case	RF Ground	

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Outline Drawing (ZZ1322)



Outline Dimensions (inch)

В С D F Κ O Н J L M Ν 1.25 1.25 0.75 0.63 0.38 0.6 -- 0.800 0.800 0.76 0.125 1.688 2.18 0.75 0.07 grams 31.75 31.75 19.05 16.00 9.65 15.24 -- 20.32 20.32 19.30 3.18 42.88 55.37 19.05

Additional Detailed Technical Information

Additional information is available on our web site. To access this information enter the model number on our web site home page.

Performance data, graphs

Case Style: ZZ1322

Environmental Ratings: ENV28

Pricing & Availability Information

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